



SI1051X-T1-E3 Information



For Reference Only

Part Number SI1051X-T1-E3 **Manufacturer** Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET P-CH 8V 1.2A SC89-6

Package SOT-563, SOT-666

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI1051X-T1-E3 Specifications

Manufacturer Part Number	SI1051X-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-563, SOT-666
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	8V
Current - Continuous Drain (Id) @ 25°C	-
Drive Voltage (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs(th) (Max) @ Id	1V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	9.45nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	560pF @ 4V
Vgs (Max)	±5V
FET Feature	-
Power Dissipation (Max)	236mW (Ta)
Rds On (Max) @ Id, Vgs	122 mOhm @ 1.2A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	SC-89-6
Package / Case	SOT-563, SOT-666
	Report errors?

SI1051X-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI1051X-T1-E3 Payment Methods



















SI1051X-T1-E3 Shipping Methods













If you have any question about SI1051X-T1-E3, please do not hesitate to contact us!

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